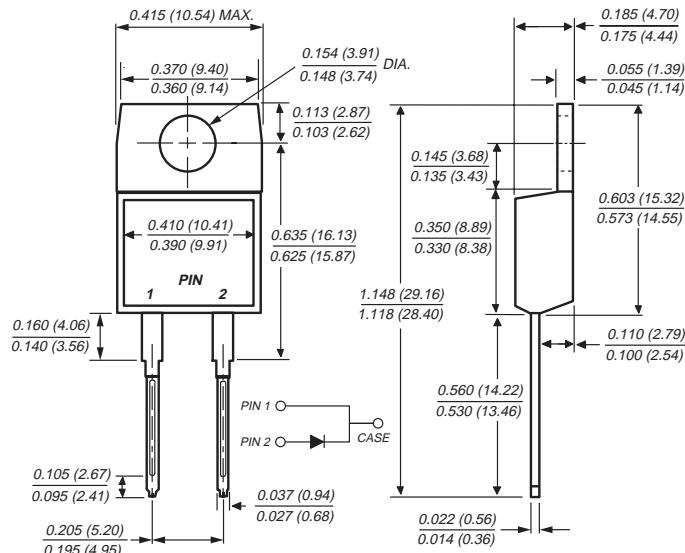


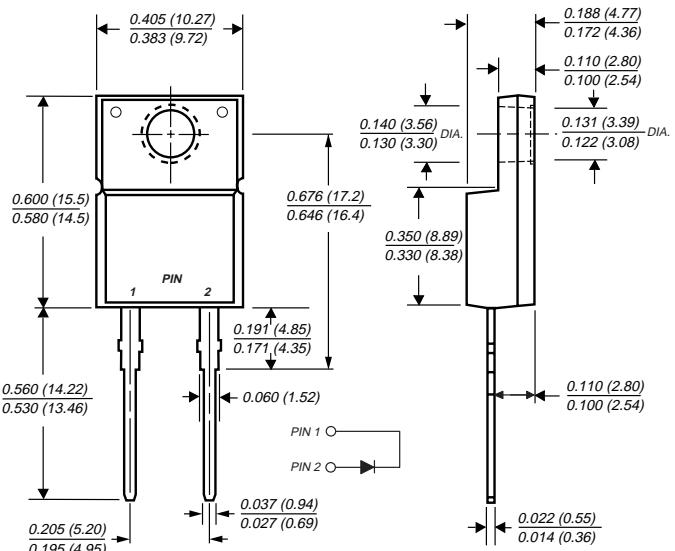
Schottky Barrier Rectifiers

Reverse Voltage 35 to 60 V
 Forward Current 10 A

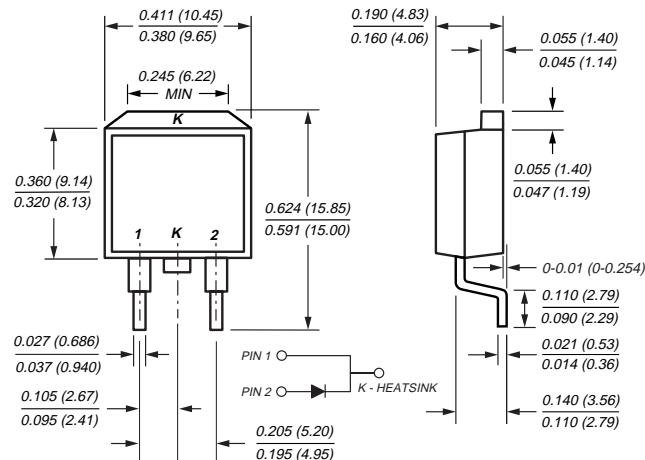
TO-220AC (MBR10Hxx)



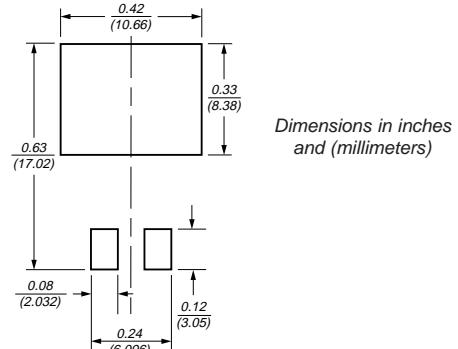
ITO-220AC (MBRF10Hxx)



TO-263AB (MBRB10Hxx)



Mounting Pad Layout TO-263AB



Features

- Plastic package has Underwriters Laboratory Flammability Classification 94 V-0
- Metal silicon junction, majority carrier conduction
- Low forward voltage drop, low power loss and high efficiency
- Guardring for overvoltage protection
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- High temperature soldering guaranteed: 250 °C/10 seconds, 0.25" (6.35 mm) from case
- Rated for reverse surge and ESD
- 175 °C maximum operation junction temperature

Mechanical Data

Case: JEDEC TO-220AC, ITO-220AC & TO-263AB molded plastic body

Terminals: Plated leads, solderable per MIL-STD-750, Method 2026

Polarity: As marked

Mounting Position: Any

Mounting Torque: 10 in-lbs maximum

Weight: 0.08 oz., 2.24 g

MBR10Hxx, MBRF10Hxx & MBRB10Hxx Series



Vishay Semiconductor

formerly General Semiconductor

Maximum Ratings (T_C = 25 °C unless otherwise noted)

Parameter	Symbol	MBR10H35	MBR10H45	MBR10H50	MBR10H60	Unit
Maximum repetitive peak reverse voltage	V _{RMM}	35	45	50	60	V
Working peak reverse voltage	V _{RWM}	35	45	50	60	V
Maximum DC blocking voltage	V _{DC}	35	45	50	60	V
Maximum average forward rectified current (See fig.1)	I _{F(AV)}			10		A
Peak repetitive forward current at T _C = 150 °C (20 KHz sq. wave)	I _{FRM}			20		A
Non-repetitive avalanche energy at 25 °C, I _{AS} = 4 A, L = 10 mH	E _{AS}			80		mJ
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}			150		A
Peak repetitive reverse current at t _p = 2.0 µs, 1 KHz	I _{RRM}		1.0		0.5	A
Peak non-repetitive reverse energy (8/20 µs waveform)	E _{RSR}		20		10	mJ
Electrostatic discharge capacitor voltage Human body model: C = 100 pF, R = 1.5 kΩ	V _C			25		kV
Voltage rate of change (rated V _R)	dV/dt			10,000		V/µs
Operating junction temperature range	T _J			−65 to +175		°C
Storage temperature range	T _{STG}			−65 to +175		°C
RMS Isolation voltage (MBRF type only) from terminals to heatsink with t = 1.0 second, RH ≤ 30%	V _{ISOL}			4500 ⁽¹⁾ 3500 ⁽²⁾ 1500 ⁽³⁾		V

Electrical Characteristics (T_C = 25°C unless otherwise noted)

Parameter	Symbol	MBR10H35, MBR10H45		MBR10H50, MBR10H60		Unit
		Typ	Max	Typ	Max	
Maximum instantaneous forward voltage ⁽⁴⁾	V _F	—	0.63	—	0.71	V
		0.49	0.55	0.57	0.61	
		—	0.75	—	0.85	
		0.62	0.68	0.68	0.71	
Maximum instantaneous reverse current at rated DC blocking voltage ⁽⁴⁾	I _R	—	100	—	100	µA
		4.0	12	2.0	12	mA

Thermal Characteristics (T_C = 25 °C unless otherwise noted)

Parameter	Symbol	MBR	MBRF	MBRB	Unit
Maximum thermal resistance	R _{θJC}	2.0	4.0	2.0	°C/W

Notes:

- (1) Clip mounting (on case), where lead does not overlap heatsink with 0.110" offset
- (2) Clip mounting (on case), where leads do overlap heatsink
- (3) Screw mounting with 4-40 screw, where washer diameter is ≤ 4.9 mm (0.19")
- (4) Pulse test: 300 µs pulse width, 1% duty cycle

Ordering Information

Product	Case	Package Code	Package Option
MBR10H35 – MBR10H60	TO-220AC	45	Anti-Static tube, 50/tube, 2K/carton
MBRF10H35 – MBRF10H60	ITO-220AC	45	Anti-Static tube, 50/tube, 2K/carton
MBRB10H35 – MBRB10H60	TO-263AB	31 45 81	13" reel, 800/reel, 4.8K/carton Anti-Static tube, 50/tube, 2K/carton Anti-Static 13" reel, 800/reel, 4.8K/carton

Ratings and Characteristic Curves ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Fig. 1 – Forward Current Derating Curve

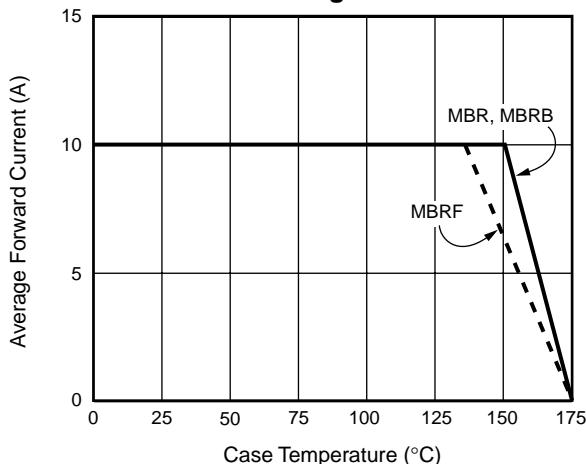


Fig. 2 – Maximum Non-Repetitive Peak Forward Surge Current

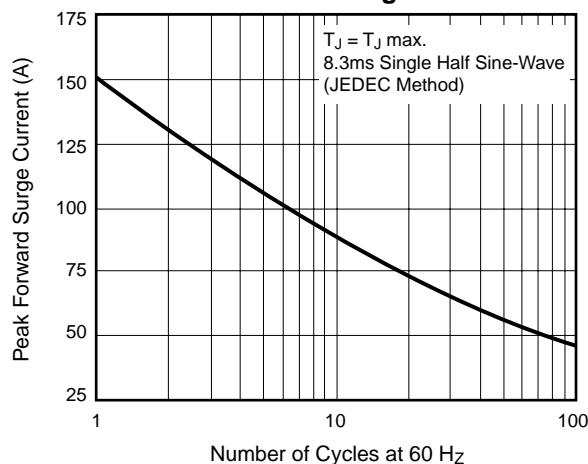


Fig. 3 – Typical Instantaneous Forward Characteristics

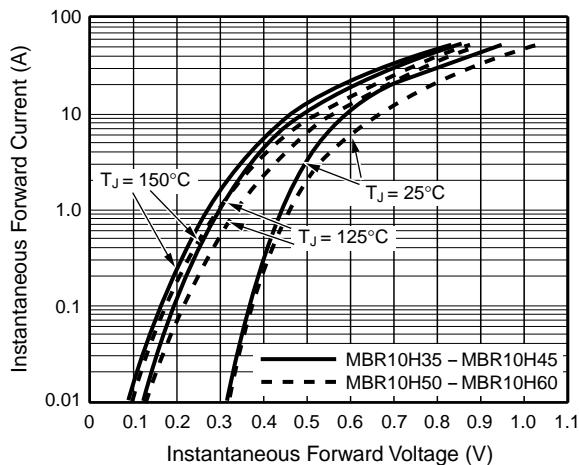


Fig. 4 – Typical Reverse Characteristics

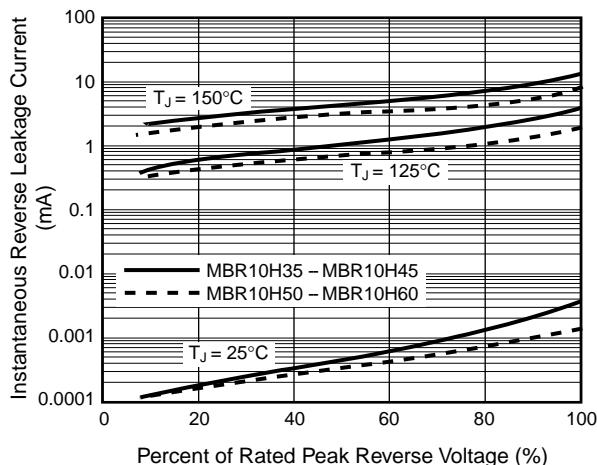


Fig. 5 – Typical Junction Capacitance

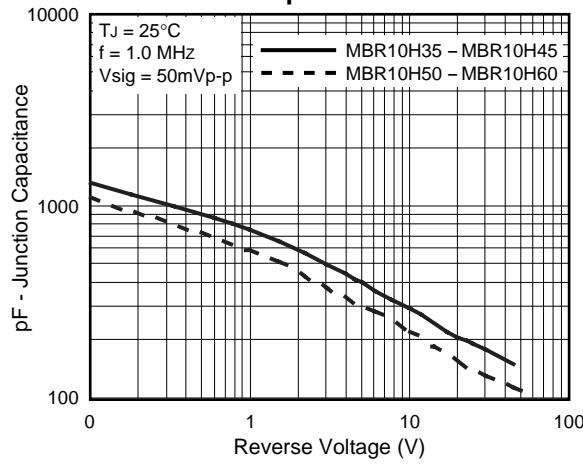


Fig. 6 – Typical Transient Thermal Impedance

